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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/646,590	08/22/2003	Takashi Kobayashi	FUJI:200A	9945
75	90 09/08/2004		EXAMINER	
Marc A. Rossi			MANDALA, VICTOR A	
ROSSI & ASSOCIATES		ART UNIT	PAPER NUMBER	
P.O. Box 826			ARTONII	FAFER NUMBER
Ashburn, VA 20146-0826			2826	

DATE MAILED: 09/08/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	-	
	10/646,590	KOBAYASHI ET AI	KOBAYASHI ET AL.	
Office Action Summary	Examiner	Art Unit		
•	Victor A Mandala Jr.	2826	p	
The MAILING DATE of this communication			ress	
Period for Reply				
A SHORTENED STATUTORY PERIOD FOR THE MAILING DATE OF THIS COMMUNIC.  - Extensions of time may be available under the provisions of after SIX (6) MONTHS from the mailing date of this commun.  - If the period for reply specified above is less than thirty (30) or If NO period for reply is specified above, the maximum status.  - Failure to reply within the set or extended period for reply will Any reply received by the Office later than three months after earned patent term adjustment. See 37 CFR 1.704(b).	ATION.  37 CFR 1.136(a). In no event, however, may a recitation.  days, a reply within the statutory minimum of thirt tory period will apply and will expire SIX (6) MON I, by statute, cause the application to become AB	eply be timely filed y (30) days will be considered timely. THS from the mailing date of this com ANDONED (35 U.S.C. § 133).	nmunication.	
Status				
1)⊠ Responsive to communication(s) filed	on 07 June 2004.			
·	)⊠ This action is non-final.			
3) Since this application is in condition for	r allowance except for formal matte	ers, prosecution as to the r	merits is	
closed in accordance with the practice	under <i>Ex parte Quayle</i> , 1935 C.D	. 11, 453 O.G. 213.		
Disposition of Claims				
4) ⊠ Claim(s) <u>34-113 and 116-118</u> is/are per 4a) Of the above claim(s) <u>96-113 and 1</u> 5) ⊠ Claim(s) <u>57,59,61,63,65,67,71,74,77,8</u> 6) ⊠ Claim(s) <u>34-56,69,70,73,75,76,81,82,8</u> 7) ⊠ Claim(s) <u>58,60,62,64,66,68,72,73,78,7</u> 8) ☐ Claim(s) are subject to restriction	116-118 is/are withdrawn from con 30,83,86,89,92 and 95 is/are allow 37,88,90 and 91 is/are rejected. 79,84,85,93 and 94 is/are objected	ed.		
Application Papers				
9) ☐ The specification is objected to by the I	Examiner.			
10) The drawing(s) filed on is/are: a	a) ☐ accepted or b) ☐ objected to	by the Examiner.		
Applicant may not request that any objection	<del>-</del> · ·	• •		
Replacement drawing sheet(s) including the 11) The oath or declaration is objected to be	· · · · · · · · · · · · · · · · · · ·	• •		
Priority under 35 U.S.C. § 119	,			
•	o forming and other walls of LLO O	440(-) (-1) (0)		
	ocuments have been received ocuments have been received in A the priority documents have been all Bureau (PCT Rule 17.2(a)).	pplication No received in this National S	itage	
Attachment(s)				
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTC</li> </ol>		Summary (PTO-413) s)/Mail Date		
<ol> <li>Notice of Draitsperson's Patent Drawing Review (PTC 3)</li> <li>Information Disclosure Statement(s) (PTC-1449 or PT Paper No(s)/Mail Date 5/26/04 &amp; 11/21/03.</li> </ol>		nformal Patent Application (PTO-	152)	

Art Unit: 2826

#### **DETAILED ACTION**

#### Election/Restrictions

1. Claims 96-113 & 116-118 withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected Group, there being no allowable generic or linking claim. Election was made without traverse in the reply filed on 6/7/04.

# **Double Patenting**

The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

2. Claims 34-36, 38, 40, 42, 44, 46, 58, 62, 69, & 87 provisionally rejected under the judicially created doctrine of double patenting over claims 22-24, 26, 28, 30, 32, 34, 37, 38, & 41 of copending Application No. 10/170216. This is a provisional double patenting rejection since the conflicting claims have not yet been patented.

The subject matter claimed in the instant application is fully disclosed in the referenced copending application and would be covered by any patent granted on that copending application since the referenced copending application and the instant application are claiming common subject matter, as follows: The claims of the copending Application teach all of the same elements as this Application, but the independent claim 22 of the copending Application is written in a different order than this Applications claim 34; thus it is obvious that it is teaching the same device.

Furthermore, there is no apparent reason why applicant would be prevented from presenting claims corresponding to those of the instant application in the other copending application. See *In re Schneller*, 397 F.2d 350, 158 USPQ 210 (CCPA 1968). See also MPEP § 804.

### Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

Subject to the following paragraph, a claim in dependent form shall contain a reference to a claim previously set forth and then specify a further limitation of the subject matter claimed. A claim in dependent form shall be construed to incorporate by reference all the limitations of the claim to which it refers.

3. Claims 35 & 36 are rejected under 35 U.S.C. 112, fourth paragraph, for not incorporating by reference all the limitations of the claim, which it refers.

Since claim 34 discloses n is expressed by n = 1.0 x Vbr/100, where Vbr is the breakdown voltage, it is unclear why claim 35 discloses an n value n = 1.5 x Vbr/100, where Vbr is the breakdown voltage and is different from that of claim 34.

It is also unclear why claim 36 discloses an n value n = 6.0 x Vbr/100, where Vbr is the breakdown voltage and is different from that of claim 34.

Application/Control Number: 10/646,590

Art Unit: 2826

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 34, 37-56, 69, 70, 73, 75, 76, 81, 82, 87, 88, 90, and 91 are rejected under 35 U.S.C. 102(b) as being anticipated by U.S. Patent No. 4,573,066 Whight.

In regards to claim 34, Whight shows all the elements of the claimed invention in Figures 1 and 3. It is a semiconductor device, comprising; a semiconductor chip (10), a low electrical resistance layer (13) of a first conductivity-type (n-type) on a bottom portion of the semiconductor chip; a breakdown-voltage sustaining layer (12) of the first conductivity type above the low electrical resistance layer; a well region (11) of the second conductivity type (p-type) in a surface portion of the breakdown voltage sustaining layer; and guard rings (1-6) of the second conductivity type in the surface portion of the semiconductor chip, the guard rings surrounding the well region, wherein the number of the guard rings (6 guard rings) being more than the number n (n = 5 when Vbr = 500 volts (col. 8, lines 41-46)) expressed by n = 1.0 x Vbr/100, where Vbr is the breakdown voltage.

Also, Whight discloses the number of the guard rings (15 guard rings) being more than the number n (n = 10 when Vbr = 1000 volts (col. 9, Iines 14-23)) expressed by n = 1.0 x Vbr/100, where Vbr is the breakdown voltage.

Application/Control Number: 10/646,590 Page 5

Art Unit: 2826

5. In regards to claims 37-56, 69, 70, 73, 75, 76, 81, & 82, Whight further discloses the difference I2-I1 between the spacing I2 (d(2) = 2  $\mu$ m) between a first of the guard rings (1), which is nearest to the well region (11) and a second of the guard rings (2), which is second nearest to the well region, (11) and the spacing I1 (d(1) = 2  $\mu$ m) between the well region (11) and the first guard ring (1) is 1  $\mu$ m or less (0  $\mu$ m). Further detailing of the claimed limitations can been seen in Table 1 Col. 6, in combination with the above explanations.

6. In regards to claim 87, 88, 90, & 91 Whight further discloses the number of the guard rings is 6, and the width of a first of the guard rings (1) (w(1) = 25  $\mu$ m), which is nearest to the well region (11), is wider than the width of a fifth of the guard rings (5) (w(5) = 10  $\mu$ m), which is fifth nearest to the well region (11).

## Allowable Subject Matter

- 7. Claims 58, 60, 62, 64, 66, 68, 72, 73, 78, 79, 84, 85, 93, & 94 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 8. The following is a statement of reasons for the indication of allowable subject matter:

  The first major difference in the claims not found in the prior art of record is the spacing between the well region and a first of the guard rings, which is nearest to the well region is, 1 pm or Iess.

  The second major difference in the claims not found in the prior ad of record is the spacing between the well region and a first of the guard rings, which is nearest to the well region, is d1/4 or less, where dl is shallower one of the junction depth of the well region and the junction depth of the guard rings.
- 9. Claims 57, 59, 61, 63, 65, 67, 71, 74, 77, 80, 83, 86, 89, 92, & 95 are allowed.

Art Unit: 2826

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Victor A Mandala Jr. whose telephone number is (571) 272-1918. The examiner can normally be reached on Monday through Thursday from 8am till 6pm..

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J Flynn can be reached on (571) 272-1915. The fax phone number for the NATHAN J. FLYNN organization where this application or proceeding is assigned is 703-872-9306. SUPERVISORY PATENT EXAMINED TECHNOLOGY CENTER 2800

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

VAMJ 9/2/04